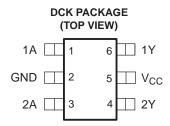


#### **FEATURES**

- Controlled Baseline
  - One Assembly Site
  - One Test Site
  - One Fabrication Site
- Extended Temperature Performance of -55°C to 125°C
- Enhanced Diminishing Manufacturing Sources (DMS) Support
- Enhanced Product-Change Notification
- Qualification Pedigree (1)
- (1) Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

- Supports 5-V V<sub>CC</sub> Operation
- Inputs Accept Voltages to 5.5 V
- Max t<sub>pd</sub> of 4.1 ns at 3.3 V
- Low-Power Consumption, 10-μA Max I<sub>CC</sub>
- ±24-mA Output Drive at 3.3 V
- Typical V<sub>OLP</sub> (Output Ground Bounce)
   <0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot)
   >2 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)



See mechanical drawings for dimensions.

#### **DESCRIPTION/ORDERING INFORMATION**

The SN74LVC2G34 is a dual buffer gate designed for 1.65-V to 5.5-V  $V_{CC}$  operation. The SN74LVC2G34 performs the Boolean function Y = A in positive logic.

NanoStar<sup>™</sup> and NanoFree<sup>™</sup> package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

#### ORDERING INFORMATION(1)

T <sub>A</sub>	PACKAGE <sup>(2)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING(3)
–55°C to 125°C	SOT (SC-70) - DCK	Reel of 3000	SN74LVC2G34MDCKREP	CAZ

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI Web site at www.ti.com.
- (2) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.
- (3) The actual top-side marking has one additional character that designates the assembly/test site.



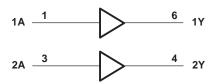
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# FUNCTION TABLE (EACH GATE)

INPUT A	OUTPUT Y
Н	Н
L	L

#### **LOGIC DIAGRAM (POSITIVE LOGIC)**



## **Absolute Maximum Ratings**(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-0.5	6.5	V
$V_{I}$	Input voltage range <sup>(2)</sup>	-0.5	6.5	V	
Vo	Voltage range applied to any output in the hig	-0.5	6.5	V	
Vo	Voltage range applied to any output in the hig	-0.5	V <sub>CC</sub> + 0.5	V	
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0 V		<b>-</b> 50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0 V		<b>–</b> 50	mA
Io	Continuous output current	·		±50	mA
	Continuous current through V <sub>CC</sub> or GND		±100	mA	
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>	DCK package		259	°C/W
T <sub>stg</sub>	Storage temperature range		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>(2)</sup> The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> The value of  $V_{CC}$  is provided in the recommended operating conditions table.

<sup>(4)</sup> The package thermal impedance is calculated in accordance with JESD 51-7.



## Recommended Operating Conditions<sup>(1)</sup>

			MIN	MAX	UNIT			
	Complements	Operating	1.65	5.5	V			
$V_{CC}$	Supply voltage	Data retention only	1.5		V			
		V <sub>CC</sub> = 1.65 V to 1.95 V	$0.65 \times V_{CC}$					
17	High lovel input valtage	$V_{CC}$ = 2.3 V to 2.7 V	1.7		\/			
$V_{IH}$	High-level input voltage	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	2		V			
		$V_{CC}$ = 4.5 V to 5.5 V	$0.7 \times V_{CC}$					
		V <sub>CC</sub> = 1.65 V to 1.95 V		$0.35 \times V_{CC}$				
V	Low level input voltage	$V_{CC}$ = 2.3 V to 2.7 V		0.7				
$V_{IL}$	Low-level input voltage	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		0.8	V			
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		$0.3 \times V_{CC}$				
$V_{I}$	Input voltage		0	5.5	V			
Vo	Output voltage		0	$V_{CC}$	V			
		V <sub>CC</sub> = 1.65 V		-4				
		$V_{CC} = 2.3 \text{ V}$		-8				
$I_{OH}$	High-level output current	V 2.V		-16	mA			
		$V_{CC} = 3 V$		-24				
		V <sub>CC</sub> = 4.5 V						
		V <sub>CC</sub> = 1.65 V		4				
		V <sub>CC</sub> = 2.3 V		8				
$I_{OL}$	Low-level output current	V 2.V		16	mA			
		V <sub>CC</sub> = 3 V		24				
		V <sub>CC</sub> = 4.5 V						
		$V_{CC}$ = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V		20				
Δt/Δν	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V			
		$V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$		5				
T <sub>A</sub>	Operating free-air temperature	,	-55	125	°C			

<sup>(1)</sup> All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. See the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



#### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN TYF	(1) MAX	UNIT
	$I_{OH} = -100 \mu A$	1.65 V to 5.5 V	V <sub>CC</sub> - 0.1		
	$I_{OH} = -4 \text{ mA}$	1.65 V	1.2		
V	$I_{OH} = -8 \text{ mA}$	2.3 V	1.9		V
V <sub>OH</sub>	$I_{OH} = -16 \text{ mA}$	3 V	2.4		V
	$I_{OH} = -24 \text{ mA}$	3 V	2.3		
	$I_{OH} = -24 \text{ mA}$	4.5 V	3.8		
	$I_{OL} = 100 \mu\text{A}$	1.65 V to 5.5 V		0.1	
	I <sub>OL</sub> = 4 mA	1.65 V		0.45	
V	I <sub>OL</sub> = 8 mA	2.3 V		0.3	V
V <sub>OL</sub>	I <sub>OL</sub> = 16 mA	3 V		0.4	
	I <sub>OL</sub> = 24 mA	3 V		0.55	
	I <sub>OL</sub> = 24 mA	4.5 V		0.55	
I <sub>I</sub> A inputs	V <sub>I</sub> = 5.5 V or GND	0 V to 5.5 V		±5	μА
I <sub>off</sub>	$V_I$ or $V_O = 5.5 \text{ V}$	0 V		±10	μА
I <sub>CC</sub>	$V_1 = 5.5 \text{ V or GND, } I_0 = 0$	1.65 V to 5.5 V		10	μА
$\Delta I_{CC}$	One input at $V_{CC}$ – 0.6 V, Other inputs at $V_{CC}$ or GND	3 V to 5.5 V		500	μА
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	3.3 V	;	3.5	pF

<sup>(1)</sup> All typical values are at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C.

## **Switching Characteristics**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1.8 V ± 0.15 V		$V_{CC}$ = 2.5 V $\pm$ 0.2 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		V <sub>CC</sub> = 5 V ± 0.5 V		UNIT	
	(INPUT)	(001701)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
t <sub>pd</sub>	Α	Υ	3.2	11.5	1.5	7	1.4	6.1	1	5.2	ns	1

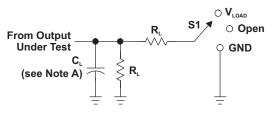
## **Operating Characteristics**

 $T_A = 25^{\circ}C$ 

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2.5 V	V <sub>CC</sub> = 3.3 V	V <sub>CC</sub> = 5 V	UNIT	
	FARAMETER	TEST CONDITIONS	TYP	TYP	TYP	TYP	UNII	
$C_{pd}$	Power dissipation capacitance	f = 10 MHz	14	14	15	17	pF	



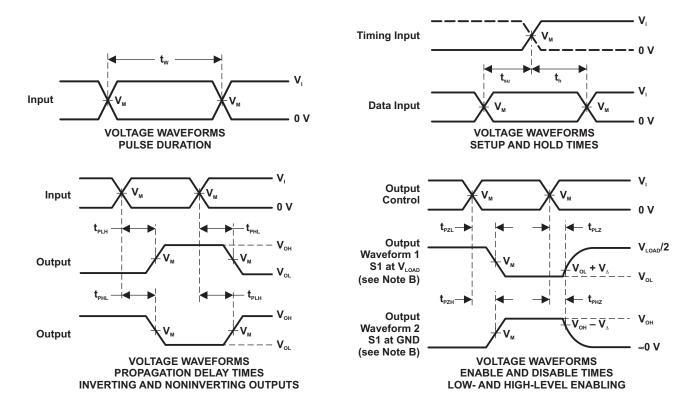
#### PARAMETER MEASUREMENT INFORMATION



TEST	S1
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	V <sub>LOAD</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

LOAD CIRCUIT

	INPUTS			W		-	W
V <sub>cc</sub>	V,	t,/t,	V <sub>M</sub>	<b>V</b> <sub>LOAD</sub>	C <sub>L</sub>	R <sub>L</sub>	V <sub>Δ</sub>
1.8 V ± 0.15 V	V <sub>cc</sub>	≤2 ns	V <sub>cc</sub> /2	2 × V <sub>cc</sub>	30 pF	<b>1 k</b> Ω	0.15 V
2.5 V ± 0.2 V	V <sub>cc</sub>	≤2 ns	V <sub>cc</sub> /2	2 × V <sub>cc</sub>	30 pF	500 Ω	0.15 V
3.3 V ± 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
5 V ± 0.5 V	V <sub>cc</sub>	≤2.5 ns	V <sub>cc</sub> /2	2 × V <sub>cc</sub>	50 pF	500 Ω	0.3 V



NOTES: A.  $C_L$  includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>o</sub> = 50  $\Omega$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{\text{PLZ}}$  and  $\dot{t}_{\text{PHZ}}$  are the same as  $t_{\text{dis}}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

www.ti.com 20-May-2025

#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
SN74LVC2G34MDCKREP	Active	Production	SC70 (DCK)   6	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CAZ
V62/06659-01XE	Active	Production	SC70 (DCK)   6	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CAZ

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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#### OTHER QUALIFIED VERSIONS OF SN74LVC2G34-EP:

Catalog: SN74LVC2G34

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



## **PACKAGE OPTION ADDENDUM**

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NOTE: Qualified Version Definitions:

 $_{\bullet}$  Catalog - TI's standard catalog product

## PACKAGE MATERIALS INFORMATION

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## TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC2G34MDCKREP	SC70	DCK	6	3000	180.0	8.4	2.4	2.5	1.2	4.0	8.0	Q3

www.ti.com 24-Apr-2020



#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC2G34MDCKREP	SC70	DCK	6	3000	202.0	201.0	28.0



SMALL OUTLINE TRANSISTOR



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

  4. Falls within JEDEC MO-203 variation AB.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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